

500 mA Negative Voltage Regulators

The MC79M00 series of fixed output negative voltage regulators are intended as complements to the popular MC78M00 series devices.

Available in fixed output voltage options of -5.0, -8.0, -12 and -15 V, these regulators employ current limiting, thermal shutdown, and safe-area compensation – making them remarkably rugged under most operating conditions. With adequate heatsinking they can deliver output currents in excess of 0.5 A.

- No External Components Required
- Internal Thermal Overload Protection
- Internal Short Circuit Current Limiting
- Output Transistor Safe-Area Compensation
- Also Available in Surface Mount DPAK (DT) Package

DEVICE TYPE/NOMINAL OUTPUT VOLTAGE

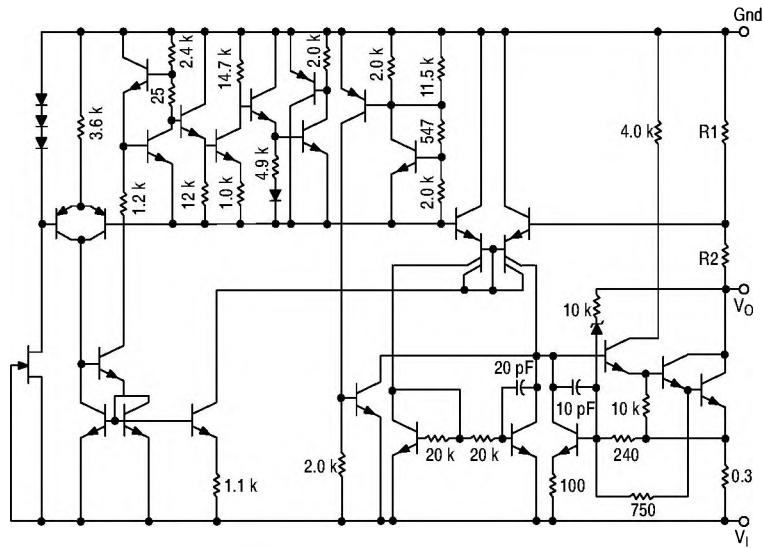
MC79M05	-5.0 V	MC79M12	-12 V
MC79M08	-8.0 V	MC79M15	-15 V

ORDERING INFORMATION

Device	Output Voltage Tolerance	Operating Temperature Range	Package
MC79MXXBDT, BDT-1	4.0%	$T_J = -40^\circ \text{ to } +125^\circ\text{C}$	DPAK
MC79MXXBT			Plastic Power
MC79MXXCDT, CDT-1		$T_J = 0^\circ \text{ to } +125^\circ\text{C}$	DPAK
MC79MXXCT			Plastic Power

XX indicates nominal voltage.

Representative Schematic Diagram



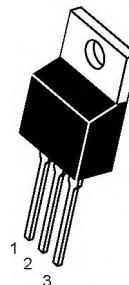
MC79M00 Series

THREE-TERMINAL NEGATIVE FIXED VOLTAGE REGULATORS

T SUFFIX
PLASTIC PACKAGE
CASE 221A

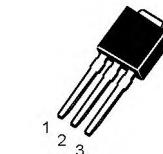
Heatsink surface
connected to Pin 2.

Pin 1. Ground
2. Input
3. Output



DT SUFFIX
PLASTIC PACKAGE
CASE 369A
(DPAK)

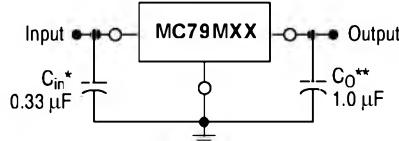
Heatsink surface (shown as terminal 4 in case outline drawing) is connected to Pin 2.



DT-1 SUFFIX
PLASTIC PACKAGE
CASE 369
(DPAK)

Heatsink surface (shown as terminal 4 in case outline drawing) is connected to Pin 2.

STANDARD APPLICATION



A common ground is required between the input and the output voltages. The input voltage must remain typically 1.1 V more negative even during the high point of the input ripple voltage.

XX, These two digits of the type number indicate nominal voltage.

* C_{in} is required if regulator is located an appreciable distance from power supply filter.

** C_O improve stability and transient response.

MC79M00

MAXIMUM RATINGS ($T_A = 25^\circ\text{C}$, unless otherwise noted.)

Rating	Symbol	Value	Unit
Input Voltage	V_I	-35	Vdc
Power Dissipation Case 221A $T_A = 25^\circ\text{C}$ Thermal Resistance, Junction-to-Ambient Thermal Resistance, Junction-to-Case	P_D θ_{JA} θ_{JC}	Internally Limited 65 5.0	W °C/W °C/W
Case 369 and 369A (DPAK) $T_A = 25^\circ\text{C}$ Thermal Resistance, Junction-to-Ambient Thermal Resistance, Junction-to-Case	P_D θ_{JA} θ_{JC}	Internally Limited 92 6.0	W °C/W °C/W
Storage Junction Temperature	T_{stg}	-65 to +150	°C
Junction Temperature	T_J	150	°C

NOTE: ESD data available upon request.

THERMAL CHARACTERISTICS

Characteristic	Symbol	Value	Unit
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$	65	°C/W
Thermal Resistance, Junction-to-Case	$R_{\theta JC}$	5.0	°C/W

MC79M05B, C

ELECTRICAL CHARACTERISTICS ($V_I = -10\text{ V}$, $I_O = 350\text{ mA}$, T_{low} to T_{high} [Note 2], unless otherwise noted.)

Characteristic	Symbol	Min	Typ	Max	Unit
Output Voltage ($T_J = 25^\circ\text{C}$)	V_O	-4.8	-5.0	-5.2	Vdc
Line Regulation, $T_J = 25^\circ\text{C}$ (Note 1) -7.0 Vdc $\geq V_I \geq$ -25 Vdc -8.0 Vdc $\geq V_I \geq$ -18 Vdc	Reg_{line}	- -	7.0 2.0	50 30	mV
Load Regulation, $T_J = 25^\circ\text{C}$ (Note 1) 5.0 mA $\leq I_O \leq$ 500 mA	Reg_{load}	-	30	100	mV
Output Voltage -7.0 Vdc $\geq V_I \geq$ -25 Vdc, 5.0 mA $\leq I_O \leq$ 350 mA	V_O	-4.75	-	-5.25	Vdc
Input Bias Current ($T_J = 25^\circ\text{C}$)	I_{IB}	-	4.3	8.0	mA
Input Bias Current Change -8.0 Vdc $\geq V_I \geq$ -25 Vdc, $I_O = 350\text{ mA}$ 5.0 mA $\leq I_O \leq$ 350 mA, $V_I = -10\text{ V}$	ΔI_{IB}	- -	-	0.4 0.4	mA
Output Noise Voltage, $T_A = 25^\circ\text{C}$, 10 Hz $\leq f \leq$ 100 kHz	V_n	-	40	-	µV
Ripple Rejection ($f = 120\text{ Hz}$)	RR	54	66	-	dB
Dropout Voltage $I_O = 500\text{ mA}$, $T_J = 25^\circ\text{C}$	$V_I - V_O$	-	1.1	-	Vdc
Average Temperature Coefficient of Output Voltage $I_O = 5.0\text{ mA}$, $0^\circ\text{C} \leq T_J \leq 125^\circ\text{C}$	$\Delta V_O / \Delta T$	-	0.2	-	mV/°C

NOTES: 1. Load and line regulation are specified at constant temperature. Change in V_O due to heating effects must be taken into account separately. Pulse testing with low duty cycle is used.

2. B = T_{low} to T_{high} , $-40^\circ\text{C} < T_J < 125^\circ\text{C}$
C = T_{low} to T_{high} , $0^\circ\text{C} < T_J < 125^\circ\text{C}$

MC79M00

MC79M08B, C

ELECTRICAL CHARACTERISTICS ($V_I = -10\text{ V}$, $I_O = 350\text{ mA}$, T_{low} to T_{high} [Note 2], unless otherwise noted.)

Characteristic	Symbol	Min	Typ	Max	Unit
Output Voltage ($T_J = 25^\circ\text{C}$)	V_O	-7.7	-8.0	-8.3	Vdc
Line Regulation, $T_J = 25^\circ\text{C}$ (Note 1) $-7.0\text{ Vdc} \geq V_I \geq -25\text{ Vdc}$ $-8.0\text{ Vdc} \geq V_I \geq -18\text{ Vdc}$	Reg_{line}	- -	5.0 3.0	80 50	mV
Load Regulation, $T_J = 25^\circ\text{C}$ (Note 1) $5.0\text{ mA} \leq I_O \leq 500\text{ mA}$	Reg_{load}	-	30	100	mV
Output Voltage $-7.0\text{ Vdc} \geq V_I \geq -25\text{ Vdc}$, $5.0\text{ mA} \leq I_O \leq 350\text{ mA}$	V_O	-7.6	-8.0	-8.4	Vdc
Input Bias Current ($T_J = 25^\circ\text{C}$)	I_{IB}	-	-	8.0	mA
Input Bias Current Change $-8.0\text{ Vdc} \geq V_I \geq -25\text{ Vdc}$, $I_O = 350\text{ mA}$ $5.0\text{ mA} \leq I_O \leq 350\text{ mA}$, $V_I = -10\text{ V}$	ΔI_{IB}	- -	- -	0.4 0.4	mA
Output Noise Voltage, $T_A = 25^\circ\text{C}$, $10\text{ Hz} \leq f \leq 100\text{ kHz}$	V_n	-	60	-	μV
Ripple Rejection ($f = 120\text{ Hz}$)	RR	54	63	-	dB
Dropout Voltage $I_O = 500\text{ mA}$, $T_J = 25^\circ\text{C}$	$V_I - V_O$	-	1.1	-	Vdc
Average Temperature Coefficient of Output Voltage $I_O = 5.0\text{ mA}$, $0^\circ\text{C} \leq T_J \leq 125^\circ\text{C}$	$\Delta V_O/\Delta T$	-	0.4	-	$\text{mV}/^\circ\text{C}$

MC79M12B, C

ELECTRICAL CHARACTERISTICS ($V_I = -19\text{ V}$, $I_O = 350\text{ mA}$, T_{low} to T_{high} [Note 2], unless otherwise noted.)

Characteristic	Symbol	Min	Typ	Max	Unit
Output Voltage ($T_J = 25^\circ\text{C}$)	V_O	-11.5	-12	-12.5	Vdc
Line Regulation, $T_J = 25^\circ\text{C}$ (Note 1) $-14.5\text{ Vdc} \geq V_I \geq -30\text{ Vdc}$ $-15\text{ Vdc} \geq V_I \geq -25\text{ Vdc}$	Reg_{line}	- -	5.0 3.0	80 50	mV
Load Regulation, $T_J = 25^\circ\text{C}$ (Note 1) $5.0\text{ mA} \leq I_O \leq 500\text{ mA}$	Reg_{load}	-	30	240	mV
Output Voltage $-14.5\text{ Vdc} \geq V_I \geq -30\text{ Vdc}$, $5.0\text{ mA} \leq I_O \leq 350\text{ mA}$	V_O	-11.4	-	-12.6	Vdc
Input Bias Current ($T_J = 25^\circ\text{C}$)	I_{IB}	-	4.4	8.0	mA
Input Bias Current Change $-14.5\text{ Vdc} \geq V_I \geq -30\text{ Vdc}$, $I_O = 350\text{ mA}$ $5.0\text{ mA} \leq I_O \leq 350\text{ mA}$, $V_I = -19\text{ V}$	ΔI_{IB}	- -	- -	0.4 0.4	mA
Output Noise Voltage, $T_A = 25^\circ\text{C}$, $10\text{ Hz} \leq f \leq 100\text{ kHz}$	V_n	-	75	-	μV
Ripple Rejection ($f = 120\text{ Hz}$)	RR	54	60	-	dB
Dropout Voltage $I_O = 500\text{ mA}$, $T_J = 25^\circ\text{C}$	$V_I - V_O$	-	1.1	-	Vdc
Average Temperature Coefficient of Output Voltage $I_O = 5.0\text{ mA}$, $0^\circ\text{C} \leq T_J \leq 125^\circ\text{C}$	$\Delta V_O/\Delta T$	-	-0.8	-	$\text{mV}/^\circ\text{C}$

NOTES: 1. Load and line regulation are specified at constant temperature. Change in V_O due to heating effects must be taken into account separately. Pulse testing with low duty cycle is used.

2. $B = T_{low}$ to T_{high} , $-40^\circ\text{C} < T_J < 125^\circ\text{C}$
 $C = T_{low}$ to T_{high} , $0^\circ\text{C} < T_J < 125^\circ\text{C}$

MC79M15B, C

ELECTRICAL CHARACTERISTICS ($V_I = -23$ V, $I_O = 350$ mA, T_{low} to T_{high} [Note 2], unless otherwise noted.)

Characteristic	Symbol	Min	Typ	Max	Unit
Output Voltage ($T_J = 25^\circ\text{C}$)	V_O	-14.4	-15	-15.6	Vdc
Line Regulation, $T_J = 25^\circ\text{C}$ (Note 1) -17.5 Vdc $\geq V_I \geq$ -30 Vdc -18 Vdc $\geq V_I \geq$ -28 Vdc	Reg_{line}	- -	5.0 3.0	80 50	mV
Load Regulation, $T_J = 25^\circ\text{C}$ (Note 1) 5.0 mA $\leq I_O \leq$ 500 mA	Reg_{load}	-	30	240	mV
Output Voltage -17.5 Vdc $\geq V_I \geq$ -30 Vdc, 5.0 mA $\leq I_O \leq$ 350 mA	V_O	-14.25	-	-15.75	Vdc
Input Bias Current ($T_J = 25^\circ\text{C}$)	I_{IB}	-	4.4	8.0	mA
Input Bias Current Change -17.5 Vdc $\geq V_I \geq$ -30 Vdc, $I_O = 350$ mA 5.0 mA $\leq I_O \leq$ 350 mA, $V_I = -23$ V	ΔI_{IB}	- -	- -	0.4 0.4	mA
Output Noise Voltage, $T_A = 25^\circ\text{C}$, 10 Hz $\leq f \leq$ 100 kHz	V_n	-	90	-	μV
Ripple Rejection ($f = 120$ Hz)	RR	54	60	-	dB
Dropout Voltage $I_O = 500$ mA, $T_J = 25^\circ\text{C}$	$V_I - V_O$	-	1.1	-	Vdc
Average Temperature Coefficient of Output Voltage $I_O = 5.0$ mA, $0^\circ\text{C} \leq T_J \leq 125^\circ\text{C}$	$\Delta V_O / \Delta T$	-	-1.0	-	$\text{mV/}^\circ\text{C}$

NOTES: 1. Load and line regulation are specified at constant temperature. Change in V_O due to heating effects must be taken into account separately. Pulse testing with low duty cycle is used.

2. B = T_{low} to T_{high} , $-40^\circ\text{C} < T_J < 125^\circ\text{C}$
C = T_{low} to T_{high} , $0^\circ\text{C} < T_J < 125^\circ\text{C}$

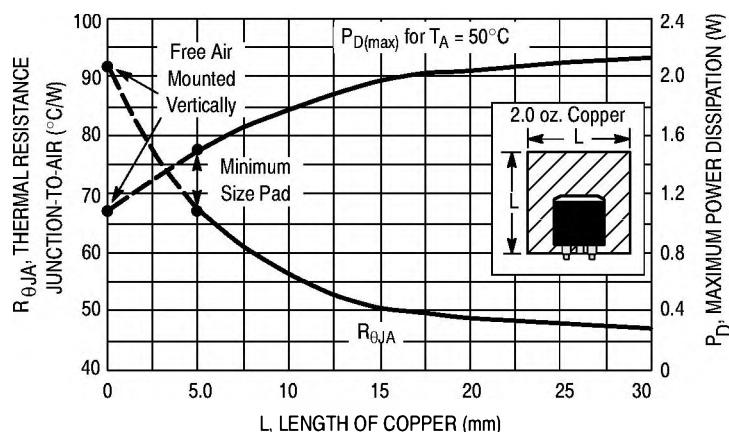


Figure 1. DPAK Thermal Resistance and Maximum Power Dissipation versus P.C.B. Copper Length